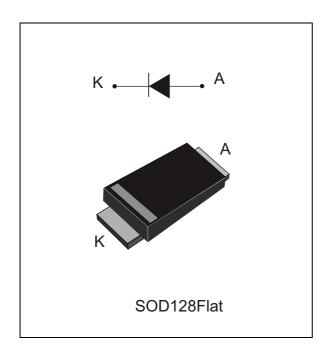
## STTH3R02-Y



### Automotive ultrafast rectifier

**Datasheet - production data** 



### **Description**

The STTH3R02-Y, implementing ST's new 200 V planar technology, is especially suited for switching mode base drive and transistor circuits. The device is also intended for use as a free wheeling diode in power supplies and other power switching applications in automotive functions.

**Table 1. Device summary** 

Symbol	Value
I <sub>F(AV)</sub>	3 A
$V_{RRM}$	200 V
T <sub>j</sub> (max)	175 °C
V <sub>F</sub> (typ)	0.72 V
T <sub>rr</sub> (typ)	16 ns

### **Features**

- · Low conduction losses
- · Negligible switching losses
- Low forward and reverse recovery times
- High junction temperature
- AEC-Q101 qualified
- ECOPACK®2 compliant component
- PPAP capable

Characteristics STTH3R02-Y

## 1 Characteristics

Table 2. Absolute ratings (limiting values at  $T_i = 25$  °C, unless otherwise specified)

Symbol	Parameter	Value	Unit		
V <sub>RRM</sub>	Repetitive peak reverse voltage	T <sub>j</sub> = -40 °C	200	V	
I <sub>F(AV)</sub>	Average forward current, square waveform	3	Α		
I <sub>FSM</sub>	Surge current non repetitive forward current	80	Α		
T <sub>stg</sub>	Storage temperature range	-65 to + 175	°C		
T <sub>j</sub> <sup>(1)</sup>	Operating temperature range -40 to + 175				

<sup>1.</sup>  $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter	Тур.	Max.	Unit
R <sub>th(j-l)</sub>	Junction to lead	15	23	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Payaraa laakaga aurrant	T <sub>j</sub> = 25 °C	V -V			1.6	^
'R`	Reverse leakage current	T <sub>j</sub> = 125 °C	$V_R = V_{RRM}$		2	16	μΑ
V <sub>E</sub> (2)	Forward voltage drop	T <sub>j</sub> = 25 °C	1 - 21		0.91	1.02	\/
VF` ′	Forward voltage drop	T <sub>j</sub> = 150 °C	$I_F = 3A$		0.72	0.83	V

<sup>1.</sup> Pulse test: tp = 5 ms,  $\delta < 2\%$ 

To evaluate the conduction losses use the following equation:

$$P = 0.71 \times I_{F(AV)} + 0.04 \times I_{F^2(RMS)}$$

<sup>2.</sup> Pulse test:  $tp = 380 \mu s$ ,  $\delta < 2\%$ 

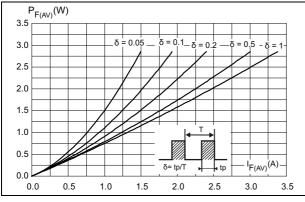
STTH3R02-Y Characteristics

Table 5. Dynamic electrical characteristics

Symbol	Parameter	Tests conditions			Тур.	Max.	Unit
		T _ 25 °C	$I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V}$		16	21	
t <sub>rr</sub>	Reverse recovery time	1 <sub>j</sub> =25 C	$I_F = 1 \text{ A, } dI_F/dt = 50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V}$		23		ns
		T <sub>j</sub> = 125 °C	$I_F = 3 \text{ A, } dI_F/dt = 200 \text{ A/}\mu\text{s,}$ $V_R = 160 \text{ V}$		24		
Q <sub>RR</sub>	Reverse recovery charge	T. = 125 °C	$I_F = 3 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s},$		50		nC
I <sub>RM</sub>	Reverse recovery current	1 j = 125 C	$^{25}$ °C $ _{F} = 3 \text{ A, dI}_{F}/\text{dt} = -200 \text{ A/}\mu\text{s,}$ $V_{R} = 160 \text{ V}$		3.5		Α

Figure 1. Average forward power dissipation versus average forward current

Figure 2. Forward voltage drop versus forward current (typical values)



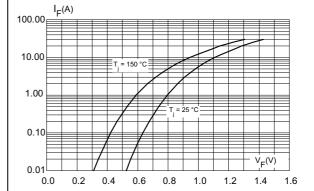
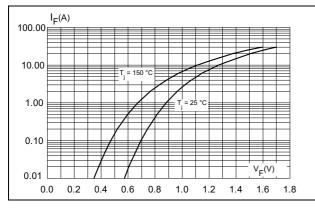
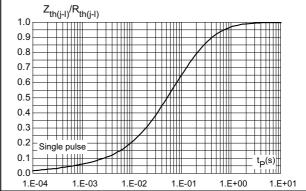


Figure 3. Forward voltage drop versus forward current (maximum values)

Figure 4. Relative variation of thermal impedance junction to lead versus pulse duration

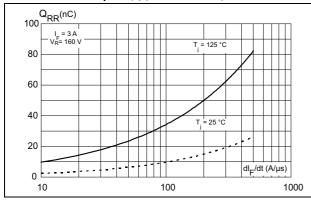




Characteristics STTH3R02-Y

Figure 5. Reverse recovery charges versus dl<sub>F</sub>/dt (typical values)

Figure 6. Reverse recovery time versus dl<sub>F</sub>/dt (typical values)



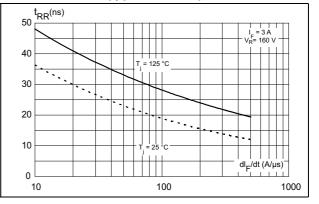
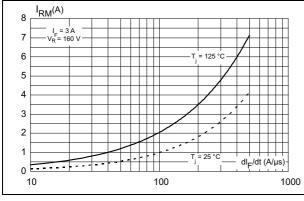


Figure 7. Peak reverse recovery current versus dl<sub>F</sub>/dt (typical values)

Figure 8. Dynamic parameters versus junction temperature



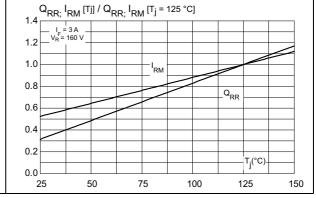
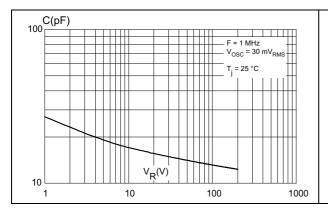
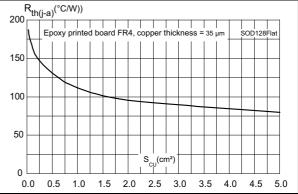


Figure 9. Junction capacitance versus reverse voltage applied (typical values)

Figure 10. Thermal resistance junction to ambient versus copper surface under each lead (typical values)





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#### **Package information** 2

- Epoxy meets UL94,V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

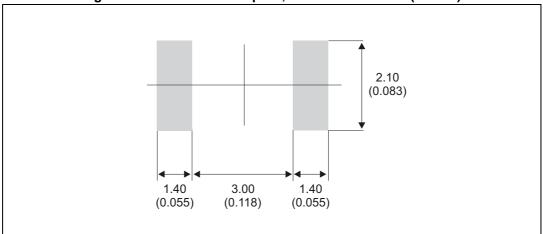
Figure 11. SOD128Flat package outline **⊉**L1 ıŢc E E1

Package information STTH3R02-Y

Table 6. SOD128Flat package mechanical data

	Dimensions					
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.93		1.03	0.037		0.041
b	1.69		1.81	0.067		0.071
С	0.10		0.22	0.004		0.009
D	2.30		2.50	0.091		0.098
Е	4.60		4.80	0.181		0.189
E1	3.70		3.90	0.146		0.154
L	0.55		0.85	0.026		0.033
L1		0.30			0.012	
L2		0.45			0.018	

Figure 12. SOD128Flat footprint, dimensions in mm (inches)



# 3 Ordering information

**Table 7. Ordering information** 

Order codes	Marking	Package	Weight	Base qty	Delivery mode
STTH3R02AFY	3R2AY	SOD128Flat	26.4 mg	3000	Tape and reel

# 4 Revision history

**Table 8. Document revision history** 

Date	Revision	Changes
24-Feb-2015	1	Initial release.

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